OSESSESS OBSIDI

Docket No. H3497 PCT/US PCT/EP99/08645

international application PCT/EP99/08645 filed on November 10, 1999, the international application not being published in English. This application also claims priority under 35 U.S.C. §119 to DE 198 53 006.4, filed on November 17, 1998. --

On page 1, on a separate line immediately after the above inserted paragraph and before line 1, please insert the following header:

-- FIELD OF THE INVENTION --.

On page 1, on a separate line between lines 5 and 6, please insert the following header:

-- BACKGROUND OF THE INVENTION -- .

On page 3, on a separate line between lines 24 and 25, please insert the following header: -- SUMMARY OF THE INVENTION -- .

On page 3, on a separate line after line 30, please insert the following header and paragraph on consecutive lines:

-- BRIEF DESCRIPTION OF THE DRAWINGS

Fig. 1 is an electron micrograph showing WDP gypsum particles useful in the present invention.

Fig. 2 is a graph showing the particle size distribution of WDP gypsum particles useful in the present invention.

On page 4, on a separate line before line 1, please insert the following header:

-- DETAILED DESCRIPTION OF THE INVENTION --.

On page 19, line 1, please replace the heading "CLAIMS" with the following heading:
-- What is claimed is: --